

Analysis of the Kondo effect in ferromagnetic atomic-sized contacts

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Atomic contacts made of ferromagnetic metals present zero-bias anomalies in the differential conductance due to the Kondo effect. These systems provide a unique opportunity to perform a statistical analysis of the Kondo parameters in nanostructures since a large number of contacts can be easily fabricated using break-junction techniques. The details of the atomic structure differ from one contact to another so that a large number of different configurations can be statistically analyzed. Here we present such a statistical analysis of the Kondo effect in atomic contacts made from the ferromagnetic transition metals Ni, Co and Fe. Our analysis shows clear differences between materials that can be understood by fundamental theoretical considerations. This combination of experiments and theory allows us to extract information about the origin and nature of the Kondo effect in these systems and to explore the influence of geometry and valence in the Kondo screening of atomic-sized nanostructures.

I. INTRODUCTION

The Kondo effect is one of the most intriguing phenomena arising from electronic correlations which was first observed over 80 years ago as a then unexpected increase of the resistance of gold wires at very low temperatures.¹ This phenomenon was successfully explained by Kondo 30 years later in his seminal work² as due to scattering of conduction electrons off magnetic impurities present in the Au samples, thereby screening its magnetic moment. More generally, whenever a local magnetic moment is coupled to a sea of conduction electrons, the Kondo effect can arise at low enough temperatures with important consequences for the electronic and magnetic properties of the system.

Also in the case of mesoscopic devices, the Kondo effect strongly alters the electronic structure and therefore has dramatic consequences on the transport characteristics of the system. One of the simplest mesoscopic devices showing the Kondo effect is the case of a quantum dot connected in series to two metallic leads:^{3,4} When an electronic level of a quantum dot is well below the Fermi Energy of the metallic leads and the Coulomb repulsion is strong enough to prevent double occupation, the quantum dot behaves as a magnetic impurity. In this situation conduction through the quantum dot is usually strongly suppressed due to the Coulomb blockade⁵. However, at low temperatures the Kondo effect restores the conductance due to the apparition of a sharp resonance—the so-called Kondo resonance—in the spectral function of the quantum dot right at the Fermi energy of the electrodes.

The essence of the Kondo effect is the formation of a total spin-singlet state between the impurity electrons and the conduction electrons near the Fermi level⁶ below a certain critical temperature characteristic of the system, the Kondo temperature. The formation of this

Kondo singlet state gives rise to the effective screening of the magnetic moment of the impurity, and leads to the formation of a sharp resonance in the spectral density of the impurity electrons right at the Fermi level. This is the afore mentioned Kondo resonance, sometimes also called Abrikosov-Suhl resonance⁷⁻⁹. In the case of magnetic impurities in metallic host materials, the formation of the Kondo resonance in the spectral density of the impurity leads to additional scattering of the conduction electrons, resulting in the increase of the resistance of the metal at low temperatures (for a review of the Kondo effect in bulk metals with magnetic impurities see e.g. Ref. 6).

Other systems where evidence for the Kondo effect has been found by the manifestation of a Kondo resonance either in the spectral density or the conductance characteristics, include point contacts^{10,11}, different molecules containing magnetic atoms on surfaces^{12,13}, fullerenes¹⁴, carbon nanotubes contacted by metallic electrodes^{15,16} and magnetic atoms on surfaces studied by Scanning Tunneling Microscopy (STM).¹⁷⁻²⁵

In the case of magnetic adatoms on metal surfaces studied by STM, interference of different conduction channels through the atom (one of them bearing the Kondo resonance), gives rise to Fano lineshapes²⁶ in the low-bias conductance characteristics, similar to the case of a quantum dot coupled laterally to a wire.^{27,28} By fitting those lineshapes to the Fano model one can obtain different parameters that describe the characteristics of the Kondo screening in the system, i.e. the width, position and amplitude of the Kondo peak (for a review see e.g. Ref. 20). Of special relevance to our work are the STM experiments performed in the high conductance regime when the tip is brought into contact with the adatom²⁹⁻³⁷.

In a recent work we reported the observation of Kondo-Fano lineshapes in the conductance characteristics of

atomic contacts made from ferromagnetic materials³⁸. In contrast to

STM experiments where the contacted adatom can be imaged and the geometry of the system formed by the adatom and the surface can be completely characterized, break junction experiments do not allow to control the geometry of the system to the same extent (although normally give rise to some geometrical repetition³⁹). On the other hand, using break junctions it is possible to form and study a large number of different configurations.⁴⁰

The observation of the Kondo effect in ferromagnetic atomic contacts was highly unexpected for two reasons: First, given the chemical homogeneity of the atomic contacts, a deviation into magnetic impurity and a spin-degenerate Fermi sea, as required for the appearance of the Kondo effect, is not obvious at all. Second, electrodes and the contact atoms are made from a ferromagnetic material. However, Kondo effect and ferromagnetism are generally competing phenomena: For example, a strong enough magnetic field corresponding to a Zeeman energy above the binding energy of the Kondo singlet (about the Kondo temperature) will break up the singlet and thus the Kondo effect⁴¹ while, on the other hand, magnetic fields on the order of the Kondo temperature or below will lead to a splitting of the Kondo resonance as shown e.g. in Refs. 4, 42, and 43.

Likewise the Kondo resonance splits when a quantum dot is connected to ferromagnetic electrodes in the case of parallel alignment of the two electrodes' magnetic polarizations while for antiparallel alignment of the electrodes a normal Kondo effect is obtained⁴⁴⁻⁴⁷. Therefore one would expect that the coupling of the contact region to the strongly ferromagnetic bulk electrodes should either eliminate the Kondo effect completely or at least split the Kondo resonance unless the antiferromagnetic coupling between magnetic impurity and conduction electrons is strong enough compared to any other interactions.

Here as in our previous work³⁸, we propose that the Kondo effect in ferromagnetic atomic contacts originates from individual d -levels of the undercoordinated tip atoms of the nanocontact, and the Kondo screening is due to the delocalized sp -electrons which are basically spin-unpolarized. Hence the impurity or quantum dot bearing the spin consists of one or several d -levels of an individual contact atom.

In our model, depending on the material the spin of the tip atom can be localized in different d -levels. Due to the low symmetry of the contact atoms the individual d -levels couple differently to the sp -conduction electron bath, resulting in different Kondo screenings of the spin. This scenario may explain the different Kondo behaviour observed for contacts made from Fe, Co and Ni.³⁸ Contacts made of the same material may also present slightly different atomic configurations which will also influence their Kondo properties. In our experiments, from the fitting of the differential conductance curves performed on atomic-sized contacts of ferromagnetic materials to a Fano expression, we extract the relevant parameters that

characterize the Kondo effect on each contact.

In this work, the validity of the Fano-Kondo model for the contact regime and more specifically for the case of atomic contacts is revised and discussed. We present a more exhaustive analysis than in Ref. 38 for all the parameters of the Fano-Kondo model in our system and extract new information from the data, for instance, the distributions for the occupation of the d -level for Fe, Co and Ni. This further analysis confirms the marked differences of the case of Ni with respect to Fe and Co. We propose here a new interpretation of the data: the nature of the Kondo screening is different for Ni contacts than for Fe and Co. From the combined statistical analysis of the Kondo parameters and theoretical fundamental considerations, we can deduce the influence of valence and environment on the Kondo screening in nanostructures.

This paper is organized as follows: The first two sections are introductory. First, we review the transport properties of atomic contacts in Sec. II. Then in Sec. III, we present the basic elements of the theory of the Kondo effect in the framework of the Anderson impurity model and justify the validity of the Fano-Kondo model for the case of atomic contacts of transition metals. Secs. IV and V are devoted to the experimental methods and the presentation and discussion of the experimental results respectively. We finally discuss the results in the framework of the theory presented in Sec. VI and summarize our main conclusions in Sec. VII.

II. TRANSPORT IN ATOMIC CONTACTS

The system under study in this work are atomic contacts⁴⁰, i.e. a contact between two metallic leads mediated by an atom forming a metallic bond with both leads. More specifically, we focus here on the case of homogeneous contacts, those where all the atoms forming the structure, leads and contact, are of the same element. The formation of an atomic contact can be identified from electronic transport measurements. When two pieces of the same pure metal are brought into contact, the conductance plotted against the inter-electrode distance shows a plateau when the atomic contact is formed, close to the quantum of conductance $G_0 = 2e^2/h$. The exact value of this quantity will depend on the material and the atomic configuration of the contact. In general, the atomic orbitals will define a number of eigen-channels, each of these with a transmission probability T_i which will be reflected in the total conductance through the Landauer formula $G = G_0 \sum_i T_i$. The number of channels will be related to the valence of the metal^{48,49} and will normally include a high transmissive s -type channel and several other with lower transmission, resulting in a final conductance in the range of 0.7-2.5 G_0 . Experimentally the evolution of the conductance can be recorded over the formation or breaking process of the contact showing in most of the cases⁵⁰ plateaus, not only for the one-atom contact but for every atomic rearrangement of

the wire while pulling.

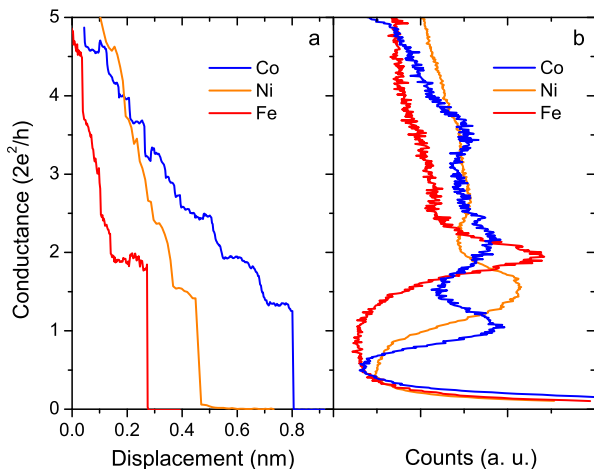


FIG. 1. (a) Typical traces of conductance for breaking contacts of Co, Fe and Ni. (b) Histograms of conductance are constructed from thousands of these breaking traces of contacts fabricated by STM at 4.2 K for Ni, Fe or Co. The histograms for the three materials show a clear first peak at values above $2e^2/h$.

The one-atom plateau of conductance for the case of gold is near the quantum of conductance and, as shown in Fig. 1a, higher for the case of the 3d-transition metals Fe, Co and Ni. From many of these traces we can build histograms which help us to identify the transport properties of the most probable atomic configurations of the contacts.

Different authors^{51,52} agree that under cryogenic conditions and considering a high enough amount of data (thousands of conductance traces), the conductance of monatomic contacts made from Fe, Co or Ni takes a value higher than the quantum of conductance $G_0 = 2e^2/h$, as expected in general for transition metals.⁴⁰ Histograms of conductance of Fe, Co and Ni constructed from thousands of breaking traces at 4.2 K are shown in Fig. 1b. The most probable values for the conductance of the monatomic contacts are $1.2 G_0$, $1.6 G_0$ and $2G_0$ for Co, Ni and Fe, respectively. Conductance values between $1 G_0$ and $2 G_0$ for ferromagnetic nanocontacts are in overall agreement with theoretical calculations.^{53–56} The conduction of these atomic contacts is the sum of the contributions of different channels, where the *s*-channel is expected to be open and practically degenerate in spin and thus to have an associated conductance of nearly $2e^2/h$. In the ferromagnetic metals Fe, Co and Ni another contribution to the overall conductance comes from the transmission of electrons via the five 3d-orbitals. However, due to the directionality and stronger localization of the *d*-orbitals, the electrons in the *d*-channels are easily scattered. Hence the transmission in *d*-channels is usually far from perfect as has been shown by *ab initio* calculations⁵³. In this work it was also shown, that only

the *d*-channels are spin-polarized while the *s*-channel basically is unpolarized.

III. BASIC ELEMENTS OF THE THEORY

As discussed in the introduction, in the experiments the presence of the Kondo effect is reflected in the conductance of a one-atom contact as a zero-bias anomaly. The details of this anomaly can be related to the characteristics of the Kondo effect in the framework of the Anderson impurity model (AIM).⁵⁷ The purpose of this section is to provide the basic elements for a theoretical description of the Kondo effect in the framework of the single-level Anderson impurity model (1AIM) and the two-level Anderson impurity model (2AIM). This will allow us to properly analyse our experiments for different materials. Additionally, we develop a simple microscopic model in order to understand the occurrence of different Fano lineshapes within the same material in terms of the variation of microscopic interactions due to variation in the atomic structure in the contact region.

A. Model of a nanocontact

We assume that the Kondo effect takes place in the under coordinated tip atoms of the nanocontact. This assumption seems reasonable considering that the Kondo effect is not observed in bulk samples of the ferromagnetic materials studied here. Hence the Kondo effect must be related to the atomic-size constriction of the nanocontact. Furthermore, the Coulomb interaction and the localization of the electrons within the atomic-size constriction, and especially at the tip atoms should be enhanced as compared to bulk.

Typically, the nanocontacts of the ferromagnetic metals Fe, Co and Ni form dimers in the last step before breaking^{58,59} as illustrated by the cartoon in Fig. 2(a). In his case each tip atom will be more strongly coupled to one electrode than to the other. As was said before in Sec. II the main conduction channel through the tip atoms is the spin-degenerate *s*-channel with nearly perfect transmission. The *d*-channels on the other hand are strongly spin-polarized and their transmission is weaker or even completely blocked due to scattering by the geometry.⁵³ As we have shown in our previous work³⁸ by means of *ab initio* calculations, due to disorder and low coordination in the contact region one of the *d*-levels of the tip atom couples only very weakly to the *d*-levels of the neighbouring atoms, and instead only couples to the basically spin-degenerate *s*-channel. Now this is the situation where the Kondo effect can take place and which is described by the Anderson impurity model: A strongly interacting *d*-level couples to a non-interacting sea of conduction electrons. Hence we can identify this *d*-level with the “quantum dot” or impurity in our experiments. This situation is schematically depicted in Fig. 2(b).

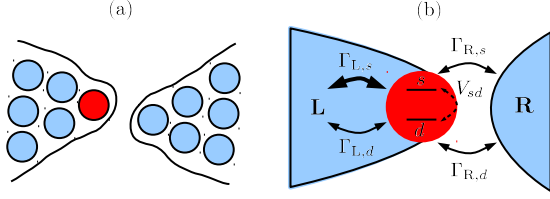


FIG. 2. (a) Cartoon of nanocontact just before breaking. The tip atom (red) of the left electrode is only weakly coupled to the right part of the nanocontact (and vice versa). This leads to the simplified model of the nanocontact as shown in (b). In the simplified model the tip atom (red) consists of a non-interacting s -level and a strongly interacting d -level which couple more strongly to the left electrode than to the right electrode ($\Gamma_{L,\alpha} > \Gamma_{R,\alpha}$). The hybridization V_{sd} between s - and d -level is due to crystal field splitting and is weak compared to the other energies. Also the coupling of the d -level to the electrodes is much weaker than the coupling of the s -level ($\Gamma_s \gg \Gamma_d$).

This scenario is further supported by recent Dynamical Mean-Field Theory calculations of a Ni nanocontact connected to electrodes made from Cu instead of Ni, thus neglecting the ferromagnetic coupling to the bulk electrodes.⁶⁰ In this situation a Kondo effect emerges in one of the d -channels of the tip atoms of the Ni nanocontact with the Kondo temperature in good agreement with the ones measured for Ni nanocontacts.

B. Kondo effect in the Anderson model

As we have argued in our previous work on the basis of *ab initio* calculations the combined effect of under coordinated tip atoms and disorder in the contact region can lead to the selection of a single d -level of the tip atom that is only weakly coupled to the d -levels of the neighbouring atoms. Hence the magnetic coupling to the neighbouring atoms is reduced for this level and therefore the Kondo effect can arise if this level is half-filled. This situation can be fulfilled in the case of Ni nanocontacts where the d -shell is d^9 and thus has a hole. In this case the single-level Anderson impurity model (1AIM) where a single strongly interacting d -level is coupled to a bath of non-interacting conduction electrons is a good description of the situation:

$$\hat{\mathcal{H}}_{\text{AIM}} = \epsilon_d \hat{n}_d + U \hat{n}_{d\uparrow} \hat{n}_{d\downarrow} + \sum_{q,\sigma} \epsilon_q \hat{c}_{q\sigma}^\dagger \hat{c}_{q\sigma} + \sum_{q,\sigma} (V_q \hat{c}_{q\sigma}^\dagger \hat{d}_\sigma + V_q^* \hat{d}_\sigma^\dagger \hat{c}_{q\sigma}) \quad (1)$$

where ϵ_d is the energy of the d -level, U is the (effective) Coulomb repulsion between two electrons in the d -level, ϵ_q is the energy dispersion of the bath electrons, and V_q is the coupling (or hopping) between the bath and the d -level. In the case of Fe and Co there is more than

one hole in the d -shell and hence one should consider a multi-level AIM. We will do so in the next subsection.

At zero temperature the Anderson model is a Fermi liquid and hence has a (renormalized) quasi-particle resonance (i.e. the Kondo peak in the Kondo regime) near the Fermi level. The Green's function of the d -level is given by:

$$G_d(\omega) = \frac{z}{\omega - \epsilon_K + i\Gamma_K} \quad (2)$$

where z is the quasi-particle weight (i.e. the renormalization of the single-particle wave-function due to many-body effects), ϵ_K is the position of the quasi-particle peak with respect to the Fermi level (set to zero for convenience), and $\Gamma_K = kT_K$ is half the width of the quasi-particle resonance which defines the Kondo Temperature. Correspondingly, the projected density of state of the d -level is a Lorentzian centred at ϵ_K and width $2\Gamma_K$:

$$\rho_d(\omega) = -\frac{1}{\pi} \text{Im} G_d(\omega) = \frac{z\Gamma_K/\pi}{(\omega - \epsilon_K)^2 + \Gamma_K^2} \quad (3)$$

In the case of the single-level AIM, the Kondo temperature T_K can be easily calculated from the parameters of the model as follows:⁶

$$\Gamma_K = kT_K = \frac{\sqrt{\Gamma_d U}}{2} e^{\pi\epsilon_d(\epsilon_d + U)/\Gamma_d U} \quad (4)$$

where Γ_d is the broadening of the d -level due to the coupling to the bath obtained by integrating out the bath degrees of Freedom:

$$\Gamma_d = V^2 \rho_{\text{bath}}(\omega = 0) \quad (5)$$

Here we have assumed an approximately constant bath density of states ρ_{bath} and the coupling V independent of q . Note the exponential dependence of the Kondo temperature on the interaction U and broadening Γ_d . This means that mild changes in the parameters can have a huge effect on the Kondo temperature. Also note that other definitions of the Kondo temperature may differ by a constant prefactor.

Since the 1AIM is a Fermi liquid at zero temperature⁶¹ we can exploit further relations of the Fermi liquid theory. For example, one obtains the following important relationship between the impurity-level occupation and the Kondo parameters (see e.g. Ch. 5 in Ref. 6):

$$n_d = 1 - \frac{2}{\pi} \arctan \left(\frac{\epsilon_K}{kT_K} \right) \quad (6)$$

Also from the Fermi liquid theory of the Anderson model we obtain the following exact relation between the density of states at the Fermi level $\epsilon_F \equiv 0$ (in general not the maximum of the Kondo peak) to the occupation of the d -level and the broadening Γ_d due to the coupling of the d -level to the rest of the system:

$$\rho_d(0) = \frac{\sin^2(\frac{\pi}{2} n_d)}{\pi \Gamma_d} \quad (7)$$

Finally the *amplitude* of the Kondo resonance is

$$A_K \equiv \rho_d(\epsilon_K) = \frac{z}{\pi k T_K} \quad (8)$$

C. Underscreened Kondo effect in the multi-level Anderson model

Co and Fe feature 2 and 3 holes, respectively, in the $3d$ -shell of each atom and hence have an atomic spin $S > 1/2$ due to Hund's rule coupling. Therefore a description in terms of a 1AIM as before is problematic. Nevertheless the experimental results can be fitted very well to a 1AIM (see below and Sec. V). The explanation might be that we are really dealing with a so-called underscreened Kondo effect⁶² (UKE) where only a spin-1/2 in one of the d -levels is screened while the rest remains unscreened.

Such an UKE behaves in many ways like a normal (fully screened) $S = 1/2$ Kondo effect. For example, it is still characterized by a zero-bias anomaly resulting from a sharp resonance in the screened impurity level. Further support for this hypothesis comes from a paper by Perkins *et al.*:⁶³ They find that for an underscreened Kondo lattice, ferromagnetism and Kondo effect can in fact coexist. On the other hand, the UKE has a number of peculiar consequences such as the formation of a so-called singular Fermi liquid state characterized e.g. by the divergence of the quasi-particle weight and thermodynamic quantities such as the specific heat capacity^{64,65}. Note that in this sense the UKE is very similar to the so-called ferromagnetic Kondo effect⁶⁶ where the impurity spin couples ferromagnetically with the conduction electrons. The resulting antiscreeing of the magnetic moment by the conduction electrons also leads to the formation of a singular Fermi liquid state. The ferromagnetic Kondo effect has recently been discussed theoretically in the context of magnetic impurities in nanocontacts.^{67,68}

We consider a two-level Anderson impurity model (2AIM). This should model the situation of Co which has two holes in the d -shell. As in the case of the simple AIM, the system is divided into two subsystems: the conduction electron bath B and the impurity I with the two interacting levels. The version of the 2AIM model that is relevant for the underscreened Kondo effect is depicted schematically in Fig. 3(a): Only one of the impurity levels couples to the conduction electron bath while the coupling of the other level is negligible.^{69,70} Hence the Hamiltonian of the 2AIM is given by:

$$\begin{aligned} \hat{H}_{2\text{AIM}} &= \hat{H}_I + \hat{H}_B + \hat{H}_T \\ &= \sum_i (\epsilon_i \hat{n}_i + U \hat{n}_{i\uparrow} \hat{n}_{i\downarrow}) + U' \hat{n}_1 \hat{n}_2 - J_H \hat{\mathbf{s}}_1 \cdot \hat{\mathbf{s}}_2 \\ &\quad + \sum_{q,\sigma} \epsilon_q c_{q\sigma}^\dagger c_{q\sigma} + \sum_{q,\sigma} V_{1,q} \left(d_{1\sigma}^\dagger c_{q\sigma} + c_{q\sigma}^\dagger d_{1\sigma} \right) \end{aligned} \quad (9)$$

where $d_{i\sigma}$ ($d_{i\sigma}^\dagger$) destroys (creates) one electron in impurity level i with spin σ , and $\hat{n}_{i\sigma} = d_{i\sigma}^\dagger d_{i\sigma}$ is the occupation

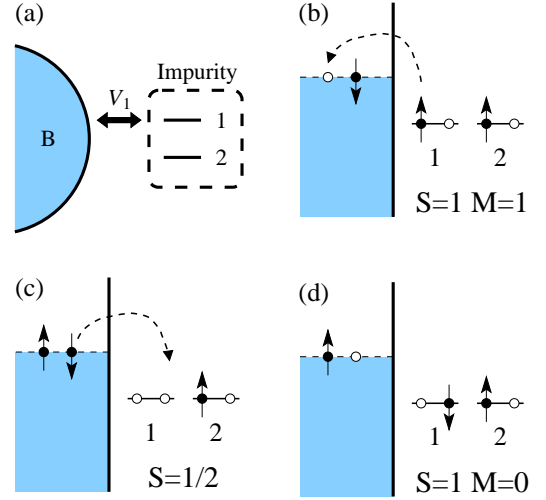


FIG. 3. (a) Schematic drawing of 2-level Anderson impurity model in the underscreened situation. Only level 1 of the impurity is coupled to the bath B. (b-d) Schematic illustration of a hopping process contributing to the underscreened Kondo effect in the 2-level Anderson impurity model.

number operator for level i and spin σ and $\hat{n}_i = \hat{n}_{i\uparrow} + \hat{n}_{i\downarrow}$. $\hat{\mathbf{s}}_i = \sum_{\sigma\sigma'} d_{i\sigma}^\dagger \vec{\tau}_{\sigma\sigma'} d_{i\sigma'}$ measures the spin in level i . ϵ_i are the energies of the two impurity levels, U is the Coulomb repulsion within the same level i and U' is the Coulomb repulsion between electrons in different levels which is generally smaller than U , and J_H is the Hund's rule coupling. The bath B is described as in the case of the 1AIM, eq. (1). Finally, only impurity level 1 is coupled to the conduction electron bath with hopping V_1 , while the coupling of impurity level 2 is negligible.

For the sake of simplicity we also assume that the two impurity levels are degenerate: $\epsilon_1 = \epsilon_2 = \epsilon$. Typically, the *intra*-level Coulomb repulsion U is bigger than the *inter*-level Coulomb repulsion U' by an amount of the order of the Hund's rule coupling: $U \approx U' + J_H$. Assuming a constant bath density of states and q -independent coupling $V_{1,q} = V_1$, the half-width of level 1 due to the coupling to the conduction electrons is given by $\Gamma_1 = V_1^2 \cdot \rho_{\text{bath}}$.

Now in the situation where the two impurity levels are well below the Fermi energy of the conduction electrons ($\epsilon_F > 2\epsilon + U'$), and the *intra*-level Coulomb repulsion U is strong enough to prevent double occupation of each impurity level ($2\epsilon + U > \epsilon_F$) the impurity will be doubly occupied. And due to Hund's rule coupling the impurity will then be in a total spin-triplet state, i.e. will have total spin $S_1 = 1$ (See App. A for further details).

In this situation, switching on the coupling H_T between the impurity and the conduction electron bath gives rise to hopping processes as depicted schematically in Fig. 3 which will *partially* screen the total spin-1 of the impurity by flipping the spin in impurity level 1. This partial screening of the impurity spin $S > 1/2$ by a sin-

gle conduction electron channel is called *underscreened Kondo effect* (UKE).⁶² The coupling to the residual spin in the other impurity level gives rise to a so-called *singular Fermi liquid* (SFL) behaviour^{64,71,72}, in contrast to the normal Fermi liquid behaviour of the usual fully screened Kondo effect.

The SFL is characterized by a cusp in the spectral density at low temperatures, i.e for low energies the spectral density of impurity level 1 is approximately given by:^{70,73}

$$\rho_1(\omega) \approx \frac{1}{\pi\Gamma_1} \left(1 - \frac{b}{\ln(|\omega|/kT_0)^2} \right) \quad (10)$$

where T_0 is a new temperature scale associated with the Spin-1 UKE and $b > 0$ is a constant. The cusp in the spectral density is related to a logarithmic divergence of the quasi-particle weight in the underscreened Kondo regime:⁶⁵ $z \propto 1/\omega \log(kT_0/\omega)$. Hence in contrast to the normal Kondo effect there is no well defined quasi-particle associated with the UKE. Hence the name *singular Fermi liquid*. Note that although the quasi-particle weight z diverges for $\omega \rightarrow 0$, the spectral density $\rho_1(\omega)$ itself does not diverge.

In an actual experiment the logarithmic cusp characteristic for the UKE is probably hard to resolve due to limited resolution and the smoothening effect of finite temperature. Hence in practice the zero-bias anomaly arising from the UKE is undistinguishable from that arising from the normal Lorentzian-type Kondo peak unless very low temperatures can be reached and the experimental resolution is fine enough to resolve the cusp.

The half width of the resulting UKE resonance is determined by the temperature T_0 as: $\Gamma_K^{S=1} = kT_0 \exp(-\sqrt{2b})$. In order to compare this width with the one of the normal Kondo peak in the 1AIM we consider the particle-hole symmetric regime. Following Ref. 70 we have $kT_0 \propto \exp\left(-\frac{\pi}{4\Gamma_1}(U + J_H/2)\right)$ while $kT_K \propto \exp(-(\pi U)/(4\Gamma_d))$. Hence for the same parameters U and $\Gamma_d = \Gamma_1$, the width of the resonance should be smaller in the case of the UKE than for the normal Kondo effect due to Hund's rule coupling J_H and the additional exponential factor $\exp(-\sqrt{2b}) < 1$. Assuming that the interaction U and coupling Γ for the d -level giving rise to the Kondo effect is approximately the same for the three transition metals considered here, this might explain why the widths of the zero-bias anomalies obtained for the cases of Fe and Co are considerably smaller than for Ni (see Sec. V).

Finally, for the 2AIM in the UKE regime one obtains exactly the same formula relating the occupation n_1 of the impurity level 1 (the one coupled to the conduction electron bath) to the width and position of the resonance as in the case of the 1AIM, eq. (6).⁷⁰ This explains why the results in the case of Co and Fe can be fitted so well to the formula for the 1AIM (see Sec. V).

D. Kondo-Fano lineshapes

The goal of this section is to devise a simple model in order to understand the occurrence of different Fano lineshapes (i.e. peaks, dips or asymmetric Fano curves) for the same material. Our simple model also demonstrates the complicated dependence of the Fano parameters on the basic microscopic parameters. Fano lineshapes in a related model have recently been studied by Zitko⁷⁴ using the Numerical Renormalization Group and focusing on the temperature dependence of the Fano lineshapes. Here we neglect any temperature effects since the measured Kondo scales are much higher than the temperature of 4.2 K at which the experiments were performed. In any case the goal of this section is not to give an exact description of the conductance spectra but rather to obtain a qualitative understanding of how different lineshapes emerge and how they depend on the microscopic details of the system.

In the following we will show that the low-bias conductance ($\|eV\| \leq \Gamma_K$) of our simplified model of a nanocontact shown in Fig. 2 is well described by the Fano formula:

$$G(V) = g_{\text{off}} + \frac{A}{1+q^2} \frac{(\epsilon+q)^2}{\epsilon^2+1} \quad \text{with } \epsilon = \frac{eV - \epsilon_K}{\Gamma_K} \quad (11)$$

where g_{off} is the conductance offset, A is the amplitude of the Fano resonance and q is the Fano factor determining the shape of the Fano resonance (see Fig. 4), and as described before ϵ_K is the energy position and Γ_K the half-width of the Kondo peak in the d -level which thus determine the position and width of the resulting Fano lineshape.

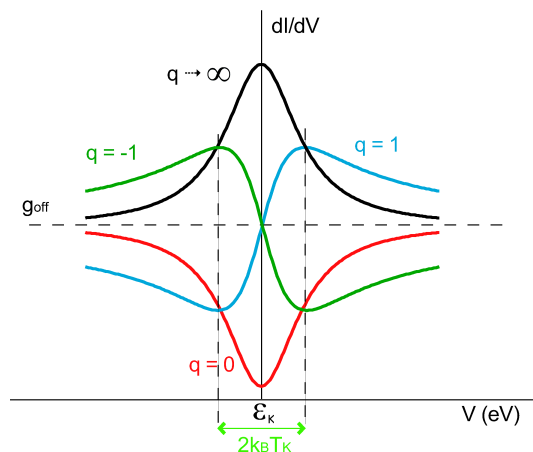


FIG. 4. Graphical definition of the Fano resonance parameters.

As can be seen from Fig. 4 when the Fano factor becomes very large ($q \rightarrow \infty$) the conductance has a Lorentzian lineshape. This is the case when the coupling V_{sd} between the s - and the d -level of our tip atom is negligible so that the zero bias anomaly in the conductance is

dominated by the direct transmission through the Kondo resonance of the d -level. On the other hand for $q = 0$ we obtain a dip-feature in the conductance. This is for example the case when the direct transmission through the d -channel becomes negligible (e.g. for $\Gamma_{R,d} \approx 0$) so that the conductance is only given by the s -channel which features a Lorentzian dip due to the coupling V_{sd} to the Kondo resonance in the d -level. For $|q| = 1$ the Fano formula gives the typical asymmetric lineshapes. In this case the conductance is also dominated by the s -channel coupled to the Kondo resonance in the d -level as for $q = 0$ but now the s -level of the tip atom is not near the Fermi level.

In the appendix we give a derivation of the Fano formula (11) for our simplified model of a nanocontact shown in Fig. 2: The (left) tip atom where the Kondo effect is taking place is modeled by one s - and one d -level. While the s -level couples well to both electrodes (via $\Gamma_{L,s}$ and $\Gamma_{R,s}$) and thus has a nearly perfect transmission, the d -level hosting the Kondo resonance has a much weaker coupling to both electrodes ($\Gamma_{L,d}$ and $\Gamma_{R,d}$). Generally we assume that the couplings to the left electrode are stronger than to the right electrode, i.e. $\Gamma_{L,\alpha} > \Gamma_{R,\alpha}$. Additionally there is a small hybridization V_{sd} between the s - and the d -level due to the crystal field.

As Meir and Wingreen showed in their landmark paper, at zero temperature and in linear response the conductance through a nanoscopic conductor is well described by the Landauer formula even in the case of a strongly interacting system.⁷⁵ The conductance G for small bias V is then given in terms of the quantum mechanical transmission function $T(\omega)$ as $G(V) = G_0 \times T(eV)$ where $G_0 = 2e^2/h$ is the fundamental conductance quantum.

As is shown in the appendix, the transmission $T(\omega)$ through the tip atom can be decomposed into the contributions of direct transmission through the individual s - and d -channel, namely $T_s(\omega)$ and $T_d(\omega)$, respectively, and a mixed channel involving hopping between both channels, $T_{sd}(\omega)$:

$$T(\omega) = T_s(\omega) + T_d(\omega) + T_{sd}(\omega) \quad (12)$$

Following eqs. (B8,B9) the direct channel transmissions T_s and T_d are given by the spectral densities of the s - and d -level, respectively, and the couplings of the s - and d -levels to both electrodes L and R .

The Kondo effect gives rise to the appearance of a Kondo resonance in the d -level spectral function $\rho_d(\omega)$ given by eq. (3). Hence the contribution of the d -channel to the total transmission has a Lorentzian lineshape:

$$T_d(\omega) = \frac{z^2 \Gamma_{L,d} \cdot \Gamma_{R,d}}{(\omega - \epsilon_K)^2 + \Gamma_K^2} = \frac{4 \Gamma_{L,d} \cdot \Gamma_{R,d}}{\Gamma_{L,d} + \Gamma_{R,d}} \cdot \frac{1}{1 + x^2} \quad (13)$$

where we have used $\Gamma_K = z(\Gamma_{L,d} + \Gamma_{R,d})/2$ and we have defined the dimensionless quantity $x = (\omega - \epsilon_K)/\Gamma_K$. Hence as pointed out above, the d -channel contribution

to the transmission can only give rise to Fano-lineshapes with $q \rightarrow \infty$.

We assume that the unperturbed s -channel (i.e. without coupling to the d -level) has a featureless (i.e. flat) and almost perfect transmission $T_s^0 \approx 1$. Due to the coupling V_{sd} to the d -level this transmission is modified according to (see appendix):

$$T_s(\omega) = T_s^0 \cdot \left[1 + \frac{2zV_{sd}^2}{\Gamma_s \cdot \Gamma_K} \cdot \frac{(x + q_0)^2 - (x^2 + 1)}{(x^2 + 1) \cdot (1 + q_0^2)} \right] \quad (14)$$

where $\Gamma_s = \Gamma_{L,s} + \Gamma_{R,s}$ is the total broadening of the s -level and the dimensionless quantity q_0 has been defined as the ratio between the s -level energy and the s -level broadening: $q_0 = -2\epsilon_s/\Gamma_s$ (see appendix for details). The second term of the r.h.s. is of the Fano form, eq. (11) and represents the modulation of the almost perfectly transmitting s -channel due to the coupling to the Kondo resonance in the d -channel. Since generally $2|\epsilon_s| < \Gamma_s$ we should have $|q_0| \leq 1$ and therefore the s -channel contribution to the transmission (14) can only give rise to dip-like ($q_0 \approx 0$) or asymmetric Fano lineshapes $q \approx 1$ but not to the peak lineshapes where $|q_0| \gg 1$.

For the mixed-channel contribution T_{sd} to the total transmission we find the following expression in the appendix:

$$T_{sd}(\omega) = T_s^0 \cdot \frac{z^2 V_{sd}^2}{\Gamma_K^2} \cdot \left(\frac{\Gamma_{R,d}}{\Gamma_{R,s}} + \frac{\Gamma_{L,d}}{\Gamma_{L,s}} \right) \cdot \frac{1}{1 + x^2} \quad (15)$$

This contribution describes transmission processes where an electron hops from one electrode to the s -level of the tip atom, subsequently to the d -level via V_{sd} , and then to the other electrode. Due to the Kondo peak in the d -level it gives rise to a Lorentzian lineshape in the transmission.

Hence we have shown that our model can give rise to all possible Fano lineshapes as obtained in the experiments. More specifically, the s -channel contribution $T_s(\omega)$ can give rise to the dip-like features ($q \approx 0$) and the asymmetric Fano features ($|q| \approx 1$) while the d -channel contribution $T_d(\omega)$ and the mixed channel contribution $T_{sd}(\omega)$ give rise to Lorentzian lineshapes ($|q| \rightarrow \infty$) in the transmission. Which term dominates depends on the specific amplitudes of the different transmission channels given by the basic parameters of our model.

It is of course possible to achieve the “canonical” Fano lineshape form for the conductance as in eq. (11) by summing up all the individual contributions to the total transmission (12) and reorganizing the terms. We then obtain a “new” Fano factor q different from the Fano factor q_0 for the pure s -channel contribution (14). This new Fano factor will depend on q_0 and the amplitudes of the individual contributions to the transmission, and yields a relatively complicated expression in terms of the basic parameters of our model. The same is true for the amplitude A of the Fano feature defined by eq. (11).

However, we can obtain quite simple expressions for q and A in eq. (11) in an important limit of our model, namely when the coupling of the d -level giving rise to the

Kondo peak to one of the electrodes becomes very small, e.g. $\Gamma_{R,d} \rightarrow 0$. In that case the direct transmission through the d -channel is strongly suppressed, i.e. $T_d \approx 0$ so that now only the mixed channel contribution T_{sd} can give rise to a Lorentzian lineshape in the transmission.

$$q = \sqrt{\frac{\Gamma_s}{\Gamma_{L,s}}} \cdot q_0 = -\frac{2\epsilon_s}{\sqrt{\Gamma_s \cdot \Gamma_{L,s}}} \quad (16)$$

$$A = \frac{1 + \Gamma_s/\Gamma_{L,s}}{1 + q_0^2} \cdot \frac{4V_{sd}^2}{\Gamma_s \cdot \Gamma_{L,d}} \\ = 2\pi \cdot \frac{\Gamma_s}{\Gamma_{L,s}} \cdot \frac{\Gamma_{L,s} + \Gamma_s}{\Gamma_s^2 + 4\epsilon_s^2} \cdot V_{sd}^2 \cdot A_K \quad (17)$$

where A_K is the amplitude of the Kondo resonance in the spectral function of the d -level as given by eq. (8). Note that the Fano factor q_0 of the s -channel transmission T_s is now scaled by the factor $\sqrt{\Gamma_s/\Gamma_{L,s}} > 1$ to yield the Fano factor q of the Fano lineshape in eq. (11) meaning that for large values of the ratio $\sqrt{\Gamma_s/\Gamma_{L,s}}$ we can obtain $|q|$ values > 1 for $0 < |q_0| \leq 1$. Furthermore, we see that the amplitude of the Fano resonance in the conductance is proportional to the amplitude of the Kondo resonance and to the square of the coupling V_{sd} between the s -level and the d -level of the tip atom.

IV. EXPERIMENTAL DETAILS

The experiments were performed using a home-made Scanning Tunnelling Microscope (STM) operated in a He cryostat at 4.2K. Two pieces of the same metal wire (Fe, Co or Ni) of 0.1 mm of diameter were scratched and sonicated in acetone and isopropanol before being mounted as 'tip and sample' in the microscope. The conductance between the two pieces of metal is obtained in a two terminal configuration by measuring the current at a fixed bias voltage, in this case 100 mV. In these conditions we can record traces of conductance while changing the distance between the two metals (a typical trace is shown in Fig. 1a) in a similar fashion as performed in other break junction experiments⁴⁰. The samples are then prepared at low temperatures by indentation until no traces with subquantum events are shown. The histograms (Fig. 1b) are similar to those at Mechanically Controlled Break Junction (MCBJ) experiments where a fresh surface is formed at cryogenic vacuum when breaking a notched wire by the controlled bending of a elastic substrate (See e.g. Ref. 40 for details). This shows that our measurements are performed over a clean spot of our samples. A strong indentation between the two electrodes is performed between the fabrication of consecutive atomic contacts to ensure the cleanliness. Our STM set-up has imaging capabilities, however, our surfaces are not atomically flat due to preparation and in order to acquire a large number of contacts to analyse no imaging is performed between contacts formation.

As described in Sec II, traces show plateaus coming from the atomic rearrangement of the wire while pulling

and the last plateau around the quantum of conductance is associated with the formation of a single atom contact. Once the conductance of the one-atom contact has been determined by the position of the first peak of the conductance histogram, we can fabricate monoatomic contacts by stopping the breaking process of the contact at the desired value of conductance within the range defined by the conductance histogram. The stability of our system allows us to maintain such an atomic contact for hours. We study the transport spectroscopy of these contacts in a similar way as performed in other transport experiments either in tunnelling or high conductance regimes (e.g. the case of quantum dot devices or the spectroscopy of adatoms by STM). We sweep the bias voltage from -100 to 100 mV while recording the dI/dV signal with the help of a lock-in amplifier when adding a 1mV AC excitation at a frequency about 1KHz to the applied bias voltage.

V. RESULTS

The fabrication of atomic contacts by using a STM (or MCBJ) offers the possibility of studying a high number of different contact configurations in a reasonable amount of time. We fabricated hundreds of atomic contacts of Fe, Co and Ni and performed electron spectroscopy measurements as described in Section IV. About 80% of these curves showed clear asymmetric profiles centred at zero bias as the ones plotted in Fig. 5.

Similar asymmetric zero bias anomalies (ZBA) were reported for ferromagnetic atomic contacts and attributed to the existence of conductance fluctuations⁷⁶ or to the existence of a magnetic domain wall.⁷⁷ On the other hand, these asymmetric profiles resemble the data reported for single magnetic adatoms in the contact regime, not only in shape but also in the energy scale of the features^{29,30}.

In our previous work we have shown clear evidence of the Kondo effect being responsible for these ZBA.³⁸ Recently, ZBA profiles, possibly of similar origin, have been reported in Refs. 78 and 79 for nanocontacts made from other materials and also show the Kondo related ZBA in adatoms contacted by ferromagnetic tips^{36,37}.

As in other Kondo systems, the asymmetric lineshapes can be fitted to the Fano equation (11). From this fitting we extract the values for the different parameters that describe the Kondo effect. As sketched in Fig. 4, the width of the resonance is directly related to the Kondo temperature (T_K). The Fano parameter q contains information about the symmetry of the lineshape. We denote by ϵ_K the energy at which the resonance is centered. As introduced in Sec. III, this parameter is associated with the energy position of the Kondo resonance and therefore to the occupation of impurity level n_d , eq. (6). Finally, A is the amplitude of the Fano profile and g_{off} the conductance offset of the curve out of the resonance.

Each realization of the contact leads to a slightly differ-

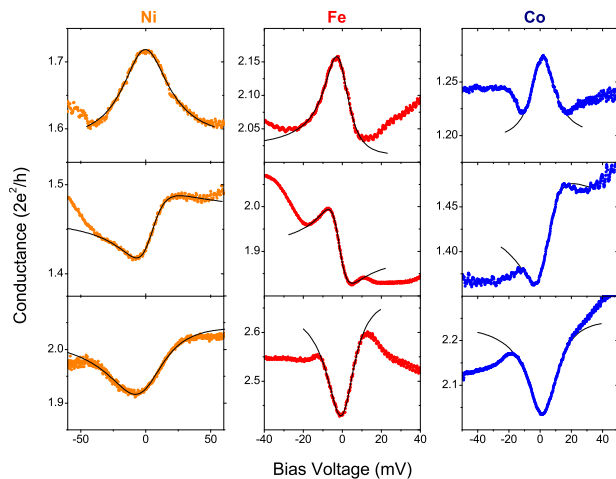


FIG. 5. Representative differential conductance curves for atomic contacts of Fe, Co and Ni. A characteristic resonance associated with the Kondo effect appears at small bias. The corresponding fit to the Fano lineshape is shown in black for each of these resonances. Due to the large differences in the width of the resonances, the fitting range is chosen so that is possible to fit the whole range of the resonance to the Fano lineshape. The selected curves exemplify different symmetry cases, from the more symmetric ($q \simeq \infty$ and $q \simeq 0$ respectively) to the clearly asymmetric ones ($q \simeq \pm 1$). While all possible symmetries seem to happen for the three materials, the width of the resonance which is associated with the Kondo temperature, is different for the three materials, especially for the case of Ni.

ent configuration. The statistical distributions of the different parameters of the Fano equation described above will reflect the subtle differences in the electronic structure of each contact. We present below a statistical analysis of each of these parameters for hundreds of contacts of Co, Fe and Ni. This novel statistical analysis (since in our previous work³⁸ we only analysed briefly the shape and mean value of the Kondo Temperature) together with theoretical considerations brings new insight into the physics of Fano-Kondo resonances. We present now the distributions of these parameters and compare the results between materials.

A. Kondo Temperatures

As described in Sec. III the zero-bias resonances observed in the conductance characteristics of Kondo systems are directly related to the resonances developed in the spectral density of the system. As explained in the theory section, the width of this resonance is determined by the energy scale of the Kondo screening, the so-called Kondo temperature T_K . Thus the width of the observed Fano lineshapes must be proportional to the Kondo temperature of the system. More precisely, we define the Kondo scale as the half width of the Fano lineshape: $\Gamma_K = k_B T_K$. The width of the measured Kondo reso-

nance is strongly affected by a finite temperature of the system: in addition to the standard thermal broadening of any differential conductance feature, the Kondo resonance presents an intrinsic thermal broadening.²⁴ This results in a considerable extra broadening of the resonance at temperatures on the order of magnitude of T_K . In our case, since the width of our resonances exceeds in more than an order of magnitude the experimental temperature of 4.2K and the bias voltages used are low enough³⁵, we can disregard thermal effects and consider that we can extract the Kondo temperature for each contact directly from the width of the Fano resonance.

As we have already described in Ref. 38, the distribution of Kondo temperatures fits a logarithmic normal distribution for the three materials Co, Fe and Ni, meaning that the logarithm of T_K is normally distributed (presented in Fig. 6). This peculiar behavior is easily understood when interpreted in terms of the Kondo effect: Since many different atomic configurations result in single-atom contacts, their electronic properties, such as conductance (Fig. 1), density of states and the associated energy scales are expected to be normally distributed. On the other hand following eq. (4) the Kondo temperature depends *exponentially* on the typical energy scales of the problem. Hence $\ln T_K$ for different contacts should follow a normal distribution if the relevant energy scales of the problem are normally distributed.

By just looking at the resonances, as for example the ones shown in Fig. 5, it can be observed that the Fano features in the conductance spectra of Ni contacts are considerably broader than the ones for the case of Co and Fe. As shown in Fig. 6 and summarized in table I, the histograms yield most frequent values for the resonance widths of $T_K = 90$ K, 120 K and 280 K for Fe, Co and Ni respectively, following the same trend $T_K^{Fe} < T_K^{Co} < T_K^{Ni}$ as in the case of adatoms of these elements deposited on non-magnetic surfaces²⁵ and diluted alloys of Cu containing the same concentration of magnetic atoms⁸⁰. In simple terms, the Kondo temperature decreases as the size of the screened magnetic moment increases, as we go from Ni to Fe.

	Fe	Co	Ni
T_K (K) in bulk Cu ⁸⁰	10-50	300-700	$\simeq 1000$
T_K (K) adatoms	—	53-92 ²³	120 ²⁵
T_K (K) this work	90	120	280
$m_{\text{atom}}(\mu B)$	3	2	1
$m_{\text{bulk}}(\mu B)$	2.22	1.72	0.60

TABLE I. A comparison of Kondo temperatures in the case of magnetic impurities in bulk Cu, magnetic adatoms in tunnelling regime and for the ferromagnetic contacts (Fe, Co and Ni) in this work. The different values of Kondo temperatures in the case of adatoms correspond to measurements performed over different substrates. Also shown are the magnetic moments of isolated atoms and in bulk.

Figure 6 shows the distribution for $\ln(T_K)$ fitted to a Gaussian distribution. Surprisingly enough, in spite of

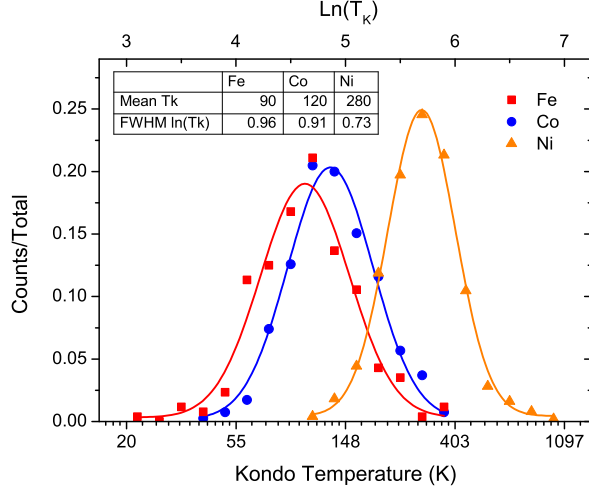


FIG. 6. Histograms of values of logarithm of Kondo temperature for Fe, Co and Ni. The histograms are normalized to the total number of counts. The distribution of values for the $\ln(T_K)$ is clearly narrower for Ni than for Fe and Co in spite of the higher value of Kondo temperatures for Ni, as summarized in the inset. The most frequent value of the Kondo temperature is determined with an error of 10 K.

showing quite higher values of Kondo temperatures, the distribution of Ni when plotted in logarithmic scale is considerably narrower than in the case of Fe and Co (see also inset of Fig. 6). This suggests that in the case of Ni the characteristics of the Kondo screening are very different from the cases of Co and Fe possibly indicating a different mechanism for the case of Ni and the cases of Co and Fe.

The higher Kondo temperatures for Ni as well as their narrower distribution could well be connected to the different chemical valence and the resulting magnetic moment in comparison to Co and Fe: While Ni basically has one hole in the $3d$ -shell and therefore features an atomic spin of $1/2$, Co and Fe have two and three holes in their $3d$ -shells associated with atomic spins of 1 and $3/2$, respectively. Hence in the case of Co and Fe the possibility exists that the full atomic spin $S > 1/2$ is only partially screened while the spin- $1/2$ in the case of Ni is fully screened by the conduction electrons. The cases of Co and Fe would then resemble the situation of an underscreened Kondo lattice where the remaining unscreened spin couples ferromagnetically to the spins on neighbouring atoms as discussed in Ref. 63. As explained in the theory section III such an underscreened Kondo effect is characterized by sharper resonances in comparison to the normal fully screened Kondo situation, and hence results in lower Kondo temperatures in the analysis. In this sense the Kondo temperatures may be underestimated in the case of Co and Fe. We discuss this in detail in the discussion section VI together with the distribution of other parameters.

B. Resonance energy (ϵ_K) and d -level occupation

Another important parameter to study is the position of the Kondo resonance ϵ_K which accounts for the deviation of the center of the Fano resonance from zero bias and is related to the energy of the effective Kondo level with respect to the Fermi energy²³. The inset of Fig. 7 shows the distribution of this parameter for hundred of contacts of the three materials under study. These distributions fit a Gaussian lineshape which is considerably broader for the case of Ni than for Co and Fe.

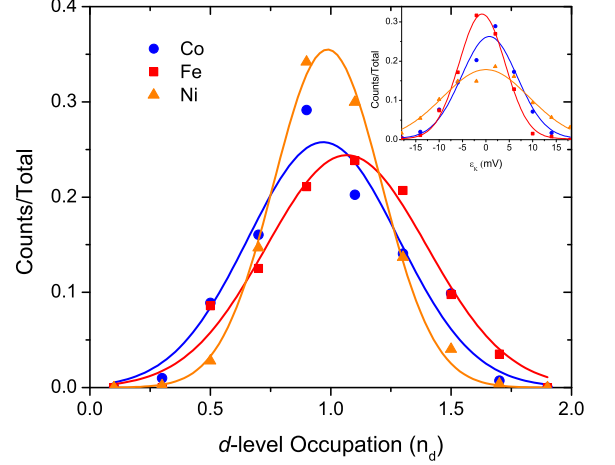


FIG. 7. Histograms of the d -level occupations n_d for contacts of Fe, Co and Ni. The color lines show the fitting of these distributions to a Gaussian peak. Surprisingly, the distribution for Ni is narrower than the other two, in spite of the fact of this material showing a broader distribution of the parameter ϵ_K . Inset: Distribution of ϵ_K for hundred of contacts of Fe, Co and Ni. This parameter accounts for the deviation of the center of the Fano resonance from zero bias and is related to the position of the localized magnetic moment in the Kondo model.

Most interestingly, from the values of ϵ_K and T_K it is possible to extract the occupation of the d -level (giving rise to the Kondo resonance) from the experimental data, assuming a Fermi liquid approximation as explained in Sec III, eq. (6). This approximation should be valid here since we are well below the Kondo temperature of our system. As explained in Sec. III, this relation is even valid for the underscreened Kondo effect in the multi-orbital Anderson model (although strictly speaking we then have a *Singular* Fermi liquid) where now n_d refers to the the d -level whose spin is screened by the conduction electrons, and ϵ_K and T_K refer to the position and width of the Kondo resonance of the underscreened Kondo effect. Fig. 7 shows the distribution of positions and the resulting calculated occupations n_d for Fe, Co and Ni which again follow a normal distribution.

As summarized in Table II the mean value for the three materials is close to 1. Interestingly, in spite of

the broader distribution of values of ϵ_K , the occupations for Ni contacts clearly show a narrower distribution. Numerically this can be explained by the much narrower distribution of $\ln(T_K)$. Physically, the reason behind the narrower distribution of Kondo temperatures and occupations in the case of Ni might be that charge fluctuations become stronger with an increasing number of active levels as already discussed in the seminal work of Nozières.⁶² In the case of Ni we are most likely dealing with a single active impurity level due to a single hole in the 3d-shell of Ni. Hence the charge in this level is quite well defined, and the occupation very close to one electron. In the cases of Co and Fe on the other hand we should have more than one active impurity level and therefore the variation in the occupation of the level giving rise to the Kondo resonance is much stronger. Relatedly, a broader distribution in the occupation of the impurity level giving rise to the Kondo resonance should also give rise to a broader distribution in the Kondo temperatures since charge fluctuations strongly alter the width of the Kondo resonance.⁶

	Fe	Co	Ni
Mean ϵ_K (mV)	-1.0	0.6	0.3
FWHM ϵ_K (mV)	14.7	16.3	25.4
Mean n_d	1.07	0.97	0.99
FWHM n_d	0.79	0.74	0.52

TABLE II. Most frequent value of Resonance energy and d-level occupations and their respective width of their Gaussian distributions for Fe, Co and Ni

C. Amplitudes

At first glance, the distribution of amplitudes in Fig. 8 shows no clear differences between the three materials. The most frequent value of the amplitude is approximately $0.1 \, 2e^2/h$, i.e. about 10 percent of the conductance of the contact. On the other hand we find that the square root of the amplitude indeed follows a normal distribution as can be seen from the inset of Fig. 8 which shows the statistical distributions of the square root of the amplitude for the three materials. A possible explanation is that following expression (17) the amplitude depends quadratically on the coupling V_{sd} between the s - and d -level of the tip atom. V_{sd} is expected to vary strongly when the atomic configuration of the contact changes since it is induced by disorder in the contact region, and is absent for perfect crystalline order. Hence if V_{sd} is normally distributed and is the parameter determining A that is most strongly affected by changing the atomic configuration of the contact one would expect \sqrt{A} to be normally distributed.

Furthermore one can see that the distributions of \sqrt{A} for the three materials are centred at quite similar values

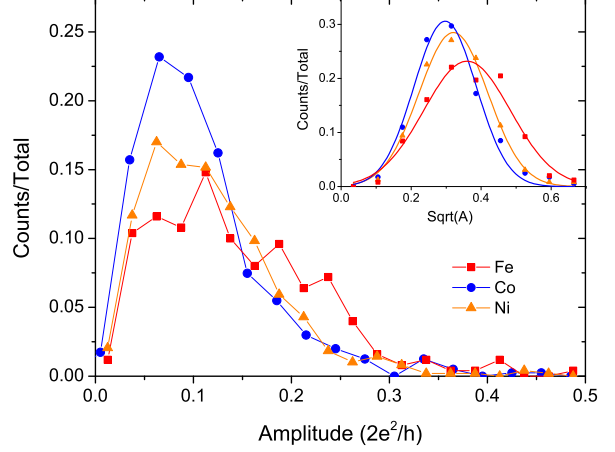


FIG. 8. Distribution of amplitudes extracted from the fitting of characteristics of hundred of contacts of Fe, Co and Ni to the Fano equation. The distributions are similar for the three materials, being the amplitudes about a 10 percent of the conductance of the contacts. The inset shows the distribution of \sqrt{A} and its fit to a Gaussian. This distribution could reflect the quadratic dependence of amplitude in different coupling terms.

and also have similar widths. However, we can make out a subtle trend (Tab. III): The mean amplitude and the mean value of the square root of the amplitude both are slightly higher for Fe contacts than for the other two materials, and also both distributions are slightly broader for Fe than for Co and Ni. However, this trend is not as clear as the trend observed in the distributions of Kondo temperatures T_K for the three materials (Fig. 6). Thus it is difficult to draw any further conclusions from it. Moreover, we would like to point out that a similar trend is observed in the distributions of the conductances (see Fig. 1 and Tab. III): Fe has a higher average conductance than Ni and Co. More data would be needed to extract further conclusions from this analysis.

	Fe	Co	Ni
Mean A from \sqrt{A}	0.13	0.088	0.10
Mean \sqrt{A}	0.36	0.30	0.32
FWHM \sqrt{A}	0.31	0.24	0.27
Mean G from Fig. 1	2.0	1.2	1.6

TABLE III. Mean values of amplitudes and width of the the gaussian distributions of \sqrt{A} and mean conductances for Fe, Co and Ni.

Far more interestingly, the plot of the amplitude versus the Kondo temperature presents an intriguing trend as can be seen from Fig. 9: For all three materials there seems to be an approximately linear dependence of the amplitude on the Kondo temperature with respect to the Kondo temperature. Moreover, when normalizing the

amplitudes and Kondo temperatures to the respective mean values (Tab.III) one obtains a *universal* dependence suggesting that $A \propto f(T_K)$.

This *universal* behaviour seems to reflect some kind of universality in the relation between the basic parameters U , ϵ_d and Γ_d that ultimately determine the Kondo properties of our system. Said in another way, the basic parameters U , ϵ_d and Γ_d are not independent from each other but are linked together in such a way that universal scaling between the amplitude A_K and the Kondo temperature T_K results. For example it is conceivable that both Γ_d (the coupling of the impurity level to the conduction electrons) and U (the effective Coulomb repulsion of the impurity level) are related since a change in the coupling Γ_d implies a change in the localization of electrons in the impurity level and hence can result in an alteration of the screening of the effective Coulomb interaction U . Further theoretical work is necessary in order to achieve a rigorous interpretation of these results.

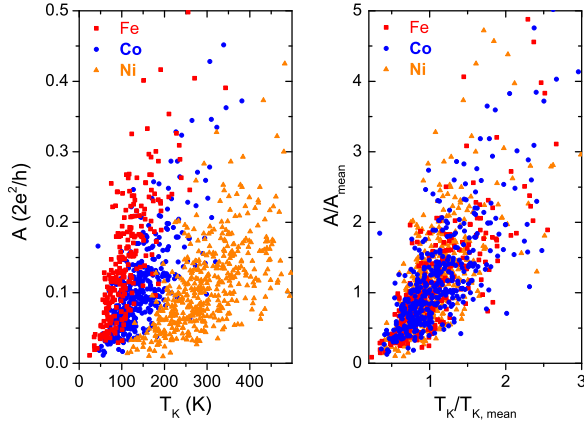


FIG. 9. Left: Scattered plot of the amplitude of the resonance versus the Kondo temperature obtained for hundreds of contacts of Fe, Co and Ni. The plot shows a clearly similar (linear) trend for the three materials. When divided by the most probable value of the Kondo temperature for each material, the distributions lay over each other, as shown in the right panel.

D. Fano Parameters

The Fano parameter q accounts for the symmetry of the Fano resonances, recovering the perfect Lorentzian shape for $q \rightarrow \infty$ and its inverse for $q = 0$. As already commented above all possible symmetries are found for each material. A histogram of the values of q for the three materials is shown in Fig. 10. Since q ranges from 0 to ∞ , an alternative representation where $q = \tan(\alpha)$ is chosen for simplicity. In this representation $\alpha = 0$ corresponds to the dip and $\alpha = \pi$ to the peak lineshapes. The totally asymmetric cases are represented by $\alpha = \pi/2$

($q = 1$) and $\alpha = 3\pi/2$ ($q = -1$). There is a remarkable preference towards the symmetric cases over the more asymmetric ones in the case of Fe and Co, and in particular the dip-like ($q = 0$) lineshapes seem to prevail. For Ni, the occurrence of asymmetric cases ($|q| \sim 1$) is considerably higher, overall the Fano factors seem to be more evenly distributed than in the case of Fe and Co.

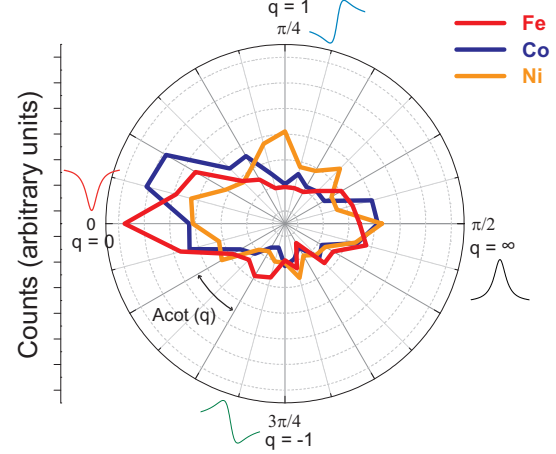


FIG. 10. The so-called Fano parameter q ranges from 0 to ∞ , but it can be expressed as $q = \tan(\alpha)$ with α between 0 and π , for simplicity in the representation. $\alpha = 0$ corresponds to the deep, $\alpha = \pi$ to the peak and $\alpha = \pi/2, 3\pi/2$ the totally asymmetric cases. The histograms are normalized to the total number of data.

In the case of adatoms in tunnelling, the symmetry is well understood in terms of the ratio between the probability of transmission through the d or the s channels²⁰. Nevertheless, in the point contact regime and in our case, the system presents a higher complexity. There is a totally open s -channel and the nature of the orbitals and couplings contributing to the interference is not completely clear. The distribution of the q parameters should contain information about the contributions from the different channels to the interference which might be extracted with the help of an appropriate theoretical treatment.

In Fig. 11 we plot the evolution of a single Co contact when stretching the junction. The symmetry of the curve changes as the contact rearranges in a different manner which translates into a different conductance of the curve (the curves are not offset). When stretching the contact the hoppings between different orbitals, the electronic structure and hence the conductance varies, this affects the interference between the conduction channels and also the Kondo resonance responsible for the Fano lineshapes. This evolution is probably specific for each contact since an attempt to find a statistical relation between q and the conductance offset results in a random distribution of points. More work is needed to fully clarify this effect.

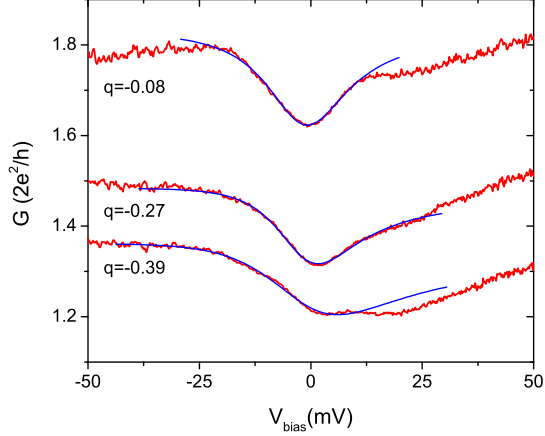


FIG. 11. Evolution of the dI/dV characteristics of a single Co contact as stretching the junction. As the conductance of the contact decreases, also the symmetry of the curve, that is the Fano parameter, q changes as a consequence of the different electronic structure of different arrangements.

E. Summary

In summary, the statistical analysis of the Fano-Kondo lineshapes extracted from hundreds of atomic contacts shows that:

(i) The statistical distribution of Kondo temperatures for each material is a log-normal distribution, i. e. the logarithm of the Kondo temperatures is normally distributed. This is expected in the context of the Kondo effect since the Kondo temperature depends exponentially on the different electronic properties and couplings of the system. These properties are likely to be normally distributed for the slightly different atomic configurations of the contacts. Hence the log-normal distribution of Kondo temperature presents further evidence that the Kondo effect is responsible for the zero-bias anomalies in the conductance.

(ii) The mean value for the Kondo temperatures is considerably higher for Ni than for Co and Fe whereas the distribution of the logarithm of the Kondo temperature for Ni is narrower than for Co or Fe. This finding suggests that possibly a different mechanism is responsible for the Kondo screening in the case of Ni than in the case of Co and Fe.

(iii) The distribution of the resonance energies ϵ_K is Gaussian and is centred around zero for all three materials. In the case of Ni this distribution is much broader than in the case of Fe and Co where the distribution widths are similar. This again points to different mechanisms for the Kondo screening for Ni on the one hand and for Co and Fe on the other hand.

(iv) The occupations n_d of the impurity level giving rise to the Kondo resonance calculated from T_K and ϵ_K by eq. (6) again follow a Gaussian distribution centered

around occupation 1. This distribution is narrower for Ni than for Co and Fe. This can be understood by considering that most likely for Ni only a single d -level is active while for Fe and Co several d -levels must be active. This leads to stronger charge fluctuations and hence a larger variation in the d -level occupations in the case of Co and Fe.

(v) The distribution of the Fano curve amplitudes does not show significant differences between the materials. We find that the square root of the amplitudes is normally distributed. This again can be understood by a normal distribution of the characteristic parameters of the nanocontacts on which the amplitude depends quadratically.

(vi) The plot of the amplitudes against the Kondo temperatures follows a similar (almost linear) trend for the three materials. When divided by the mean values for each material the data lines are perfectly on top of each other, showing a universal scaling behaviour of the amplitude with the Kondo temperature.

(vii) There are more asymmetric Fano lineshapes in the case of Ni than for Co and Fe. The distribution of Fano parameters q again is similar for Fe and Co but different for Ni. Co and Fe show a clear preference for the dip-like $q = 0$ line shapes while for Ni the distribution of the Fano parameters is somewhat more uniform.

Table IV shows a summary of the parameters extracted from the statistical analysis of the Fano-Kondo lineshapes for the all three materials.

	Fe	Co	Ni
Mean T_K	90	120	280
FWHM $\ln(T_K)$	0.96	0.91	0.73
Mean ϵ_K (mV)	-1.0	0.6	0.3
FWHM ϵ_K (mV)	14.7	16.3	25.4
Mean n_d	1.07	0.97	0.99
FWHM n_d	0.79	0.74	0.52
Mean A from \sqrt{A}	0.13	0.088	0.1
FWHM \sqrt{A}	0.31	0.24	0.27

TABLE IV. Summary of the different parameters extracted from the statistical analysis of hundreds of atomic contacts for each of the three materials Fe, Co and Ni.

VI. DISCUSSION

The picture of the Kondo effect in ferromagnetic atomic contacts that emerges from our statistical analysis and theoretical considerations is the following: The low coordination and disorder of the atoms in the contact region in connection with a higher effective Coulomb repulsion can lead to the localization of a single spin in an individual d -level of an atom in the contact region.³⁸ Now, due to disorder in the contact region it can happen that this d -level only couples very weakly to the spin-polarized d -levels on neighbouring atoms but instead it

has an effective coupling to the basically spin-unpolarized s -type conduction channel. In this situation the Kondo effect can take place and screen the spin in that d -level.

In the case of Ni there is one hole in the $3d$ -shell and therefore a spin- $1/2$ associated with it. If the spin becomes localized in a d -level that predominantly couples to the spin-unpolarized s -type conduction electrons this spin can be fully screened. Hence for Ni we should have a *normal* Kondo effect where the full spin- $1/2$ is screened. In the case of Fe and Co the atomic spin is higher due to 3 and 2 holes, respectively, in the $3d$ -shell of these atoms. This might explain why the measured Kondo temperatures are higher in the case of Ni than for Co and Fe since the Kondo temperature decreases with increasing spin of the impurity.^{81,82} However, one would then also expect a significantly lower Kondo temperature for Fe than for Co which is not the case.

The scenario that we propose instead for Co and Fe is an underscreened Kondo effect where the full atomic spin $S > 1/2$ is only partially screened by the conduction electrons. More precisely, only the spin- $1/2$ within the d -level that predominantly couples to the s -type conduction electrons will be screened while the rest of the spin $S - 1/2$ which is likely to be localized in d -levels that couple more strongly to the spin-polarized d -levels on neighbouring atoms, remains unscreened. This scenario fits very well with our results: In particular, it explains why the average Kondo temperature is very similar for Fe and Co but is considerably higher for Ni as the underscreened Kondo effect is characterized by a cusp-like resonance much sharper than the Lorentzian-type resonance of the normal fully screened Kondo effect. An underscreened Kondo effect for Fe and Co contacts would also explain why the occupations can be calculated from eq. (6) derived for the single-level Anderson impurity model.

A recent work by Néel *et al.*³⁷ shows how the Kondo temperature increases for a Cobalt impurity when it is contacted by an Fe tip compared to the case of using a Cu tip. These results and their interpretation are in good agreement with the results presented here: differences in the composition and geometries of the junctions lead to different electronic structure of the contact which determine the Kondo screening. By studying a specific system with a well characterized geometry, Neel *et al.* can extract the change in hybridization and the corresponding occupation of the d -level as the main cause of the observed increase in Kondo temperatures. We study here instead a large variety of possibilities. Changes in the hybridization are probably responsible for the broad distribution of Kondo temperatures in our data, but other parameters such as the occupancy of the $3d$ -shell may also change in our system from contact to contact.

Finally, we would like to discuss the connection to a related work by Bork *et al.*³⁶ with the results presented here: In the work of Bork *et al.* the Fano-Kondo lineshapes of a system consisting of two Co atoms, one on a Cu surface and the other attached to Cu STM tip are

recorded while the distance between the two Co atoms is decreased from the tunnelling regime to the contact regime. The authors report a splitting of the Fano-Kondo lineshapes when the contact regime is entered due to the formation of a spin-singlet state between the two Co atoms.

In some cases the Fano-Kondo lineshapes of the ferromagnetic contacts measured here could also be interpreted as a splitting of the Kondo resonance. For example, the evolution of the Fano lineshape of a Co nanocontact being stretched (Fig. 11) possibly shows a small splitting for the curve with the lowest conductance. However, if this specific feature really shows a splitting of the Fano-Kondo resonance it actually occurs in the opposite direction as for the system studied by Bork *et al.*, i.e. it occurs when the nanocontact is pulled apart and not when the tip atoms are brought together as in the case of Bork *et al.* In any case we have not observed such curves that could be interpreted as splittings very frequently, and the focus of this work is a statistical analysis of a large number of different configurations of atomic contacts while the work of Bork *et al.* focuses on a very specific system. On the other hand we also would like to point out that conductance oscillations in the spectroscopy at the atomic scale⁸³ further complicate the interpretation of this kind of curves.

Still one might wonder why splitting of the Fano-Kondo lineshapes in the atomic contacts studied here are not observed more frequently. The reason might be that indeed the d -level on a tip atom giving rise to the Kondo effect just does not couple very well to the d -levels of the other tip atom due to the disorder in the contact region. Hence the splitting is probably very weak compared to the Kondo temperature and therefore not observed, as also shown in Ref.³⁷, where the Kondo resonance remains unsplit even when the Co adatom is contacted by a ferromagnetic tip. Another possible explanation could be that the weak coupling between the d -levels giving rise to the Kondo effect localized on different tip atoms is compensated by the weak spin polarization of the conduction electrons similar to the case of a double quantum dot coupled to ferromagnetic leads.⁸⁴

VII. CONCLUSIONS

Atomic contacts are a unique system to understand the dramatic consequences of low coordination and disorder on the electronic transport and magnetic properties at the nanoscale. The emergence of the Kondo effect in atomic contacts is a good example for this.³⁸ Here we have extended our previous work in several aspects in order to gain new insights into the nature of the Kondo effect in ferromagnetic one-atom contacts: We have presented an exhaustive statistical analysis of the Fano resonances in the spectroscopy of ferromagnetic one-atom contacts. In particular, we have analysed not only the distribution of Kondo temperatures, but also of the res-

onance energies, amplitudes and Fano parameters. Such an exhaustive statistical analysis has never been performed before for any Kondo system, and it provides us with new information on the nature of the Kondo effect in these system.

From this analysis we have for example obtained the distribution of d -level occupations, and the dependence of the amplitudes of the Fano resonance on the Kondo temperature. We also point out the widths of the parameter distributions as an indicator on the robustness of the Kondo screening in one-atom contacts of the different materials. Additionally, we have further developed the theory in order to explain the observed qualitative differences between Ni on the one hand and Co and Fe on the other hand. Furthermore, we have devised a simple microscopic model which allows us to understand the occurrence of different Fano lineshapes for the same material in terms of variations of the microscopic interactions.

Our statistical analysis shows clear differences in the Kondo characteristics of different ferromagnetic materials, i.e. of Fe and Co versus Ni. These differences can be explained by the different valences, leading to different Kondo scenarios. Although this might not be a unique explanation for the observed phenomenology, the reported results seem to fit well with an underscreened Kondo effect for the case of Fe and Co, and a standard spin-1/2 Kondo model for the case of Nickel.

While the different screening conditions might account for the differences in Kondo temperatures and occupation, the complexity of atomic contacts, especially of transition metals, where many different channels contribute to the transport, makes it difficult to fully understand the details for each single contact. A simple interpretation for certain parameters as the exact shape of the curves (Fano parameter) or the amplitude of the resonances is difficult to achieve as the spectroscopy might contain also information about other phenomena such as quantum oscillations due to interferences between non resonant conduction channels, inelastic processes as phonon excitations etc.

In the recent past, the combination of molecular dynamics simulations and *ab initio* transport calculations and experiment has proven to be a successful path for understanding the atomic, electronic and magnetic structure as well as the transport properties of nanocontacts.^{39,50,59} Further work in this direction in combination with more sophisticated many-body techniques capable of describing the Kondo effect such as the Dynamical Mean-Field Theory^{60,85} should contribute to fully understand Kondo physics and the presence of magnetism in these systems and in atomic-size structures in general.

VIII. ACKNOWLEDGEMENTS

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Appendix A: Two-level Anderson impurity eigenstates

Here we briefly discuss the many-body eigenstates of the *isolated* two-level Anderson impurity model and the fluctuations between them that lead to the underscreened Kondo effect as discussed in Sec. III C.

The isolated impurity Hamiltonian \hat{H}_I of the 2AIM (9) is easily diagonalized. The empty impurity state is denoted by $|d^0\rangle$ and has energy $E_0 = 0$. For single occupation the four eigenstates and energies are trivially given by

$$|d^1; i\sigma\rangle = d_{i\sigma}^\dagger |0\rangle, E_1 = \langle i\sigma | \hat{H}_I | i\sigma \rangle = \epsilon \quad (\text{A1})$$

For double occupation, the eigenstates can be separated into spin-singlet (total impurity spin $S = 0$) and spin-triplet ($S = 1$) states. The latter are given by

$$|d^2; S = 1; M\rangle = |1, 2\rangle^- \otimes \begin{cases} |\uparrow, \uparrow\rangle & (M = 1) \\ |\uparrow, \downarrow\rangle^+ & (M = 0) \\ |\downarrow, \downarrow\rangle & (M = -1) \end{cases} \quad (\text{A2})$$

where M is the projection of the total impurity spin onto the spin quantization axis. The triplet states are all degenerate with energy $E_T = 2\epsilon + U' - J_H/4$. The spin singlet states can be written as:

$$|d^2; S = 0; ij\rangle = |i, j\rangle^+ \otimes |\uparrow, \downarrow\rangle^- \quad (\text{A3})$$

The corresponding eigen energies are $E_S^{12} = 2\epsilon + U' + \frac{3}{4}J_H$ and $E_S^{11} = E_S^{22} = 2\epsilon + U$. Typically, $U \approx U' + J_H$, and therefore $E_S^{11} = E_S^{22} > E_S^{12}$. Due to Hund's rule coupling the triplet states are lower in energy by an amount $E_S^{12} - E_T = J_H$. In Fig. 12 we show the corresponding energy level diagram for the 2AIM. U and U' are assumed to be big enough to prevent triple and full occupation of the impurity. Hence the triplet states comprise the ground state manifold of the isolated impurity system.

Now in the situation of the underscreened Kondo effect where only one of the impurity levels is coupled to the conduction electron bath, hopping processes between the impurity and the bath can only lead to a spin flip in the impurity level that is coupled to the bath as illustrated in Fig. 3. These spin flip processes can only lead to fluctuations between states with $M = 1$ and $M = 0$

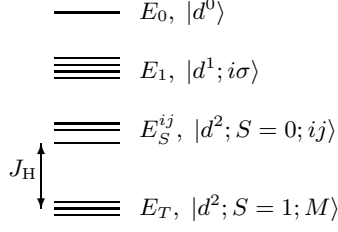


FIG. 12. Schematic energy level diagram for the (isolated) 2-level impurity described by H_1 in eq. (9).

and between states with $M = -1$ and $M = 0$. For example: $|S = 1; M = 1\rangle = |1 \uparrow, 2 \uparrow\rangle^{(-)} \xrightarrow{d_{1\uparrow}} |2 \uparrow\rangle \xrightarrow{d_{1\downarrow}^\dagger} |1 \downarrow, 2 \uparrow\rangle^{(-)} \xrightarrow{d_{1\downarrow}} |2 \uparrow\rangle \xrightarrow{d_{1\uparrow}^\dagger} |1 \uparrow, 2 \uparrow\rangle^{(-)}$. Hence the total spin of the impurity is only *partially* screened by these processes. This is the essence of the underscreened Kondo effect.

Appendix B: Derivation of the Fano formula for model contact

We assume the simplified model of a nanocontact described in Sec. III and shown in Fig. 2. We concentrate on one of the tip atoms of the nanocontact which in our model consists of an (almost) perfectly transmitting s -level and the d -level where the Kondo effect takes place. Hence the Greens function (GF) of the tip atom can be written as:

$$\mathbf{G}_A(\omega) = \begin{pmatrix} G_s & G_{sd} \\ G_{sd} & G_d \end{pmatrix} \quad (\text{B1})$$

G_d is the Green's function of the d -level which in the Kondo regime is given by eq. (2) and thus yields a Kondo resonance in the corresponding spectral function as described by eq. (3) at energy ϵ_K , half width Γ_K and the quasi particle weight z .

The unperturbed s -level GF (i.e. without coupling V_{sd} to the d -level) is given by

$$G_s^0(\omega) = \frac{1}{\omega - \epsilon_s + i\Gamma_s/2} \approx \frac{1}{-\epsilon_s + i\Gamma_s/2} \quad (\text{B2})$$

where ϵ_s is the energy of the s -level and $\Gamma_s = \Gamma_{L,s} + \Gamma_{R,s}$ the width due to coupling to both electrodes. Since the energies we are interested in are on the order of the Kondo scale, $|\omega| \approx \Gamma_K$ and $\Gamma_K \ll \Gamma_s$, we neglect the ω -dependence of G_s^0 in the last step of eq. (B2).

Now due to the coupling V_{sd} of the s -level to the d -level, the full GF G_s of the s -level is modified according to:

$$G_s(\omega) = G_s^0(\omega) + G_s^0(\omega) V_{sd} G_d(\omega) V_{sd} G_s^0(\omega) \quad (\text{B3})$$

The off-diagonal term G_{sd} describes the interference between both channels due to the coupling V_{sd} , and is given by:

$$G_{sd}(\omega) = V_{sd} \cdot G_s^0 \cdot G_d(\omega) \quad (\text{B4})$$

As was shown by Meir and Wingreen in their seminal work⁷⁵, at zero temperature and in linear response the exact result for the conductance and current through an interacting region reduces to the Landauer result where the transmission function can be calculated from the Caroli formula⁸⁶. Using the Caroli formula we can calculate the coherent transmission via the tip atom as

$$T(\omega) = \text{Tr}[\mathbf{\Gamma}_L \mathbf{G}_A^\dagger \mathbf{\Gamma}_R \mathbf{G}_A] \quad (\text{B5})$$

where $\mathbf{\Gamma}_L$ and $\mathbf{\Gamma}_R$ are the so-called coupling matrices describing the coupling of the tip atom A to the left and right electrodes:

$$\mathbf{\Gamma}_\alpha = \begin{pmatrix} \Gamma_{\alpha,s} & 0 \\ 0 & \Gamma_{\alpha,d} \end{pmatrix} \quad \text{with } \alpha \in \{L, R\} \quad (\text{B6})$$

Hence we find for the transmission $T(\omega)$ through the tip atom:

$$T(\omega) = T_s(\omega) + T_d(\omega) + T_{sd}(\omega) \quad (\text{B7})$$

where T_s is the direct transmission through the s -channel and T_d the corresponding one through the d -channel while T_{sd} describes the transmission involving hopping processes between the s - and d -channel:

$$T_s(\omega) = 2\pi \cdot \frac{\Gamma_{L,s} \cdot \Gamma_{R,s}}{\Gamma_s} \cdot \rho_s(\omega) \quad (\text{B8})$$

$$T_d(\omega) = 2\pi \cdot \frac{\Gamma_{L,d} \cdot \Gamma_{R,d}}{\Gamma_d} \cdot \rho_d(\omega) \quad (\text{B9})$$

$$T_{sd}(\omega) = (\Gamma_{L,s}\Gamma_{R,d} + \Gamma_{L,d}\Gamma_{R,s}) \cdot |G_{sd}|^2 \quad (\text{B10})$$

In order to calculate the contribution of the s -channel to the total transmission, we need to know the spectral density of the s -level which is given by the imaginary part of the s -level GF given by eq. (B3):

$$\rho_s(\omega) = \underbrace{-\frac{1}{\pi} \text{Im}[G_s^0(\omega)]}_{\rho_s^0(\omega)} - \underbrace{\frac{V_{sd}^2}{\pi} \cdot \text{Im}[(G_s^0(\omega))^2 \cdot G_d(\omega)]}_{\delta\rho_s(\omega)} \quad (\text{B11})$$

where ρ_s^0 is the spectral function of the unperturbed s -level which in our model is constant, $\rho_s^0 = \Gamma_s/2\pi(\Gamma_s^2/4 + \epsilon_s^2)$. $\delta\rho_s(\omega)$ is the change in the spectral density due to the coupling to the d -level with the Kondo peak. For the latter we find:

$$\begin{aligned} \delta\rho_s &= -\frac{V_{sd}^2}{\pi} \cdot \{ \text{Im}[(G_s^0)^2] \cdot \text{Re}[G_d] + \text{Re}[(G_s^0)^2] \cdot \text{Im}[G_d] \} \\ &= -\frac{V_{sd}^2}{\pi} \cdot \{ 2 \cdot \text{Re}[G_s^0] \cdot \text{Im}[G_s^0] \cdot \text{Re}[G_d] \\ &\quad + (\text{Re}[G_s^0]^2 - \text{Im}[G_s^0]^2) \cdot \text{Im}[G_d] \} \end{aligned} \quad (\text{B12})$$

The real and imaginary part of G_d are given by:

$$\text{Re } G_d(\omega) = \frac{z(\omega - \epsilon_K)}{(\omega - \epsilon_K)^2 + \Gamma_K^2} = \frac{z}{\Gamma_K} \cdot \frac{x}{x^2 + 1} \quad (\text{B13})$$

$$-\text{Im } G_d(\omega) = \frac{z\Gamma_K}{(\omega - \epsilon_K)^2 + \Gamma_K^2} = \frac{z}{\Gamma_K} \cdot \frac{1}{x^2 + 1} \quad (\text{B14})$$

where we have defined $x \equiv (\omega - \epsilon_K)/\Gamma_K$. Plugging this into eq. (B12) we find:

$$\delta\rho_s = -\frac{zV_{sd}^2}{\pi\Gamma_K} \cdot \frac{1}{x^2 + 1} \cdot \{2x \cdot \text{Re } G_s^0 \cdot \text{Im } G_s^0 - [\text{Re } G_s^0]^2 + [\text{Im } G_s^0]^2\} \quad (\text{B15})$$

We now define the ratio q between real and imaginary part of G_s^0 :

$$q \equiv -\frac{\text{Re } G_s^0}{\text{Im } G_s^0} \approx -\frac{2\epsilon_s}{\Gamma_s} \quad (\text{B16})$$

With this we find for the expression in curly brackets in eq. (B15):

$$\begin{aligned} 2x \cdot \text{Re } G_s^0 \cdot \text{Im } G_s^0 - [\text{Re } G_s^0]^2 + [\text{Im } G_s^0]^2 &= \quad (\text{B17}) \\ &= [\text{Im } G_s^0]^2 \times \left\{ 2x \cdot \frac{\text{Re } G_s^0}{\text{Im } G_s^0} - \left[\frac{\text{Re } G_s^0}{\text{Im } G_s^0} \right]^2 + 1 \right\} \\ &\approx \frac{4}{\Gamma_s^2} \frac{1}{(1 + q^2)^2} \{-2qx - q^2 + 1\} \\ &= -4 \frac{(x + q)^2 - (x^2 + 1)}{\Gamma_s^2 \cdot (1 + q^2)^2} \end{aligned}$$

Hence we obtain for the change $\delta\rho_s$ in the spectral density of the s -level due to the coupling to the d -level:

$$\delta\rho_s(\omega) = \frac{4zV_{sd}^2}{\pi\Gamma_K\Gamma_s^2} \cdot \frac{(x + q)^2 - (x^2 + 1)}{(x^2 + 1) \cdot (1 + q^2)^2} \quad (\text{B18})$$

Summing up, we find for the s -channel contribution to the transmission (14):

$$\begin{aligned} T_s(\omega) &= T_s^0 + 2\pi \cdot \frac{\Gamma_{L,s} \cdot \Gamma_{R,s}}{\Gamma_s} \cdot \delta\rho_s(\omega) \\ &= T_s^0 \cdot \left[1 + \frac{2zV_{sd}^2}{\Gamma_s \cdot \Gamma_K} \cdot \frac{(x + q)^2 - (x^2 + 1)}{(x^2 + 1) \cdot (1 + q^2)^2} \right] \quad (\text{B19}) \end{aligned}$$

where $T_s^0 = 2\pi\rho_s^0 \cdot (\Gamma_{L,s} \cdot \Gamma_{R,s})/\Gamma_s$ is the transmission via the unperturbed s -channel.

For the d -channel contribution to the total transmission we find according to eqs. (B7) and (3):

$$T_d(\omega) = 4 \frac{\Gamma_{L,d} \cdot \Gamma_{R,d}}{\Gamma_d^2} \cdot \frac{1}{x^2 + 1} \quad (\text{B20})$$

Finally, for the sd -coupling contribution to the transmission we need to calculate the absolute square of the off-diagonal matrix element G_{sd} of the atomic GF:

$$|G_{sd}(\omega)|^2 = V_{sd}^2 \cdot |G_s^0|^2 \cdot |G_d(\omega)|^2 = \frac{V_{sd}^2 z^2}{\Gamma_K^2 \cdot (1 + x^2)} \quad (\text{B21})$$

Hence we find:

$$T_{sd}(\omega) = T_s^0 \cdot \frac{z^2 V_{sd}^2}{\Gamma_K^2} \cdot \left(\frac{\Gamma_{R,d}}{\Gamma_{R,s}} + \frac{\Gamma_{L,d}}{\Gamma_{L,s}} \right) \cdot \frac{1}{1 + x^2} \quad (\text{B22})$$

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